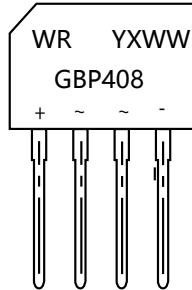


## Ultrasoft Recovery Bridge



### PINNING

PIN	DESCRIPTION
1	Input Pin (~)
2	Input Pin (~)
3	Output Anode (+)
4	Output Cathode (-)

### Features

- Glass Passivated Chip Junction
- Reverse Voltage - 800 V
- Forward Current - 4A
- High Surge Current Capability
- Designed For Surface Mount Application

### Benefits

- Case: GBP
- Terminals: Solderable Per MIL-STD-750

### Maximum Ratings and Electrical characteristics

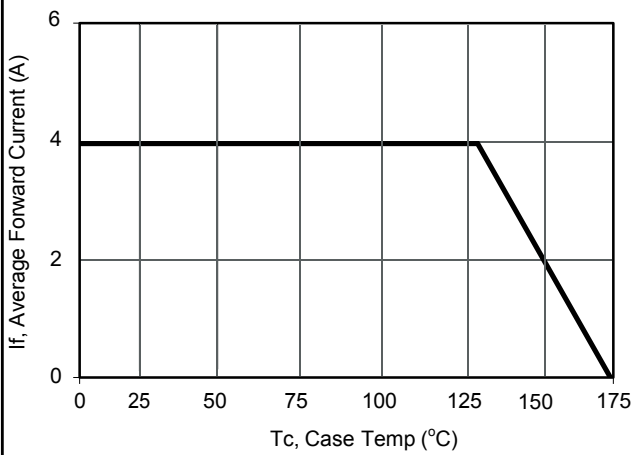
Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

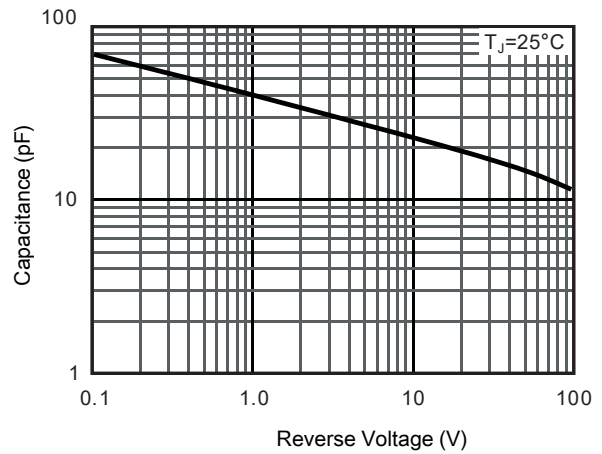
Parameter	Symbols	WRGBP408	Units
Maximum Repetitive Peak Reverse Voltage	VRRM	800	V
Maximum RMS voltage	VRMS	560	V
Maximum DC Blocking Voltage	VDC	800	V
Average Rectified Output Current	Io	4.0	A
Reverse Recovery Time. IF=0.5A,IR=1A,IRR=0.25A	Trr	10	us
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	IFSM	110	A
I <sup>2</sup> t rating for fusing ( 1ms < t < 10ms)	I <sup>2</sup> t	60.5	A <sup>2</sup> S
Maximum Forward Voltage at 2.0 A	VF	0.98	V
Maximum DC Reverse Current @TA=25 °C at Rated DC Blocking Voltage @TA=125 °C	IR	5 100	μA
Typical Junction Capacitance (Note1)	Cj	40	pF
Operating and Storage Temperature Range	Tj, Tstg	-55 ~ +175	°C

Note: 1. Measured at 1MHz and applied reverse voltage of 4 VDC.

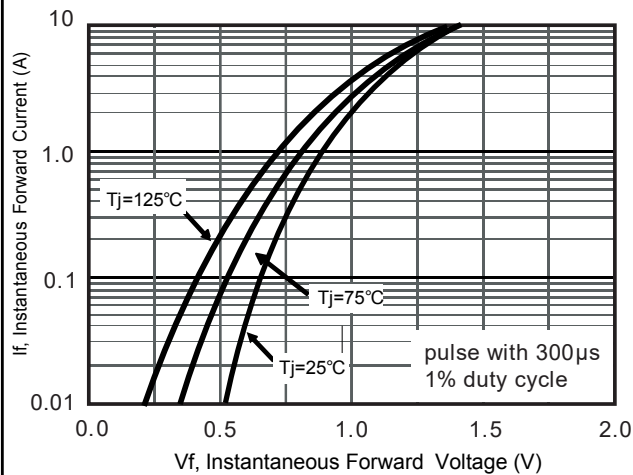
## RATINGS AND CHARACTERISTICS CURVES (TA = 25 °C unless otherwise noted)



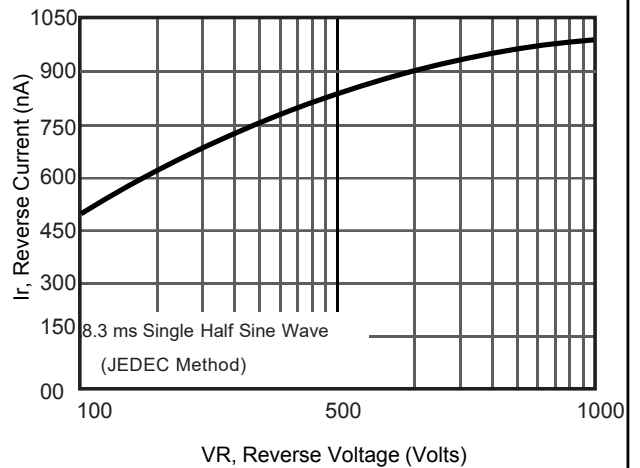
Current Derating, Case



Typical Junction Capacitance

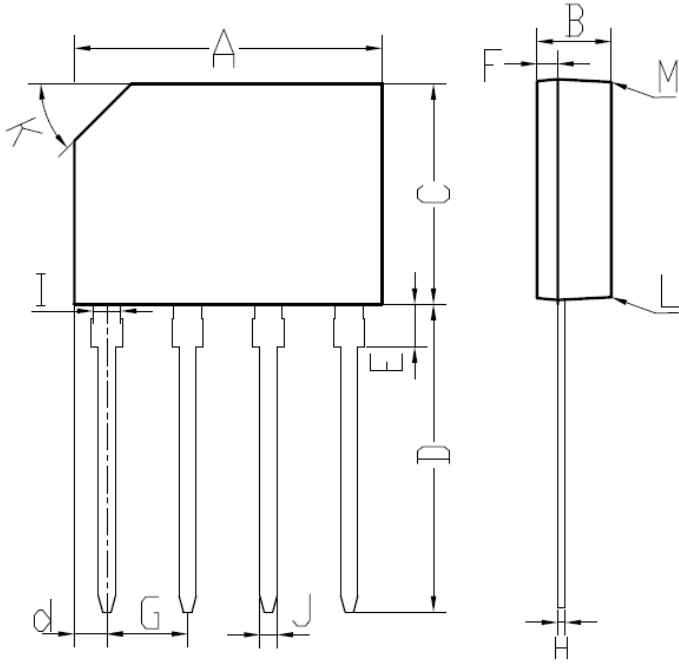


Typical Forward Voltage



Typical Reverse Current

## PACKAGE OUTLINE DIMENSIONS



GBP		
DIM.	MIN.	MAX.
A	14.20	14.70
B	3.30	3.60
C	10.20	10.60
D	13.80	14.40
d	1.40	1.70
E	1.80	2.20
F	0.80	1.10
G	3.71	3.91
H	0.30	0.55
I	1.22	1.42
J	0.76	0.86
K	2.7 x 45° (Typ)	
L	#	3°
M	#	2°
All Dimensions in millimeter		